













OPA625, OPA2625

SBOS688A - APRIL 2015-REVISED OCTOBER 2015

OPAx625 High-Bandwidth, High-Precision, Low THD+N, 16-Bit and 18-Bit Analog-to-Digital Converter (ADC) Drivers

Features

High-Drive Mode:

– GBW (G = 100): 120 MHz

Slew Rate: 115 V/µs

16-Bit Settling at 4-V Step: 280 ns

Low Voltage Noise: 2.5 nV/√Hz at 10 kHz

Low Output Impedance: 1 Ω at 1 MHz

Offset Voltage: ±100 µV (max)

Offset Voltage Drift: ±3 μV/°C (max)

Low Quiescent Current: 2 mA (typ)

Low-Power Mode:

- GBW: 1 MHz

Low Quiescent Current: 270 μA (typ)

Power-Scalable Features:

 Ultrafast Transition from Low-Power to High-Drive Mode: 170 ns

High AC and DC Precision:

 Low Distortion: –122 dBc for HD2 and –140 dBc for HD3 at 100 kHz

Input Common-Mode Range Includes Negative

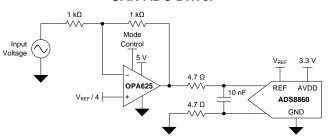
Rail-to-Rail Output

Wide Temperature Range: Fully Specified from -40°C to +125°C

2 Applications

- Precision SAR ADC Drivers
- Precision Voltage Reference Buffers
- Programmable Logic Controllers
- Test and Measurement Equipment
- Power-Sensitive Data Acquisition Systems

SAR ADC Driver



3 Description

The OPAx625 family of operational amplifiers are excellent 16-bit and 18-bit, high-precision, SAR ADC drivers with low THD and noise that allow for a unique power-scalable solution. This family of devices is fully characterized and specified with a 16-bit settling time of 280 ns that enables a true 16-bit effective number of bits (ENOB). With a high dc precision of only 100 µV offset voltage, a wide gainbandwidth product of 120 MHz, and a low wideband noise of 2.5 nV/\(\sqrt{Hz}\), this family is optimized for driving high-throughput, high-resolution SAR ADCs, such as the ADS88xx family of SAR ADCs.

The OPAx625 features two operating modes: highdrive and low-power. In the innovative low-power mode, the OPAx625 tracks the input signal allowing the device to transition from low-power mode to highdrive mode at 16-bit ENOB within 170 ns.

The OPAx625 family is available in 6-pin SOT and 10-pin VSSOP packages and is specified for operation from -40°C to +125°C.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) | | |
|-------------|------------|-------------------|--|--|
| OPA625 | SOT (6) | 2.90 mm × 1.60 mm | | |
| OPA2625 | VSSOP (10) | 3.00 mm × 3.00 mm | | |

(1) For all available packages, see the package option addendum at the end of the data sheet.

16-Bit SAR ADC, f_{IN} = 10-kHz, 1-MSPS FFT

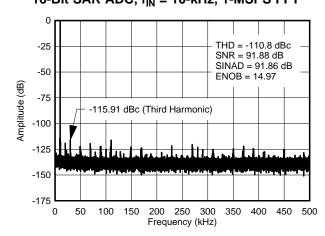




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4 Revision History

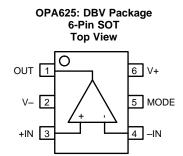
| CI | hanges from Original (April 2015) to Revision A | Page |
|----|---|------|
| • | Changed OPA2625 from product preview to production data; added OPA2625 specifications to data sheet | 1 |
| • | Changed MODE B pin description options for V+ and V- | 3 |
| • | Added crosstalk parameter to Electrical Characteristics table | 5 |
| • | Added crosstalk parameter to Electrical Characteristics table | 8 |
| • | Changed short-circuit current value from 150 mA to 80 mA in Electrical Characteristics table | 9 |
| • | Changed short-circuit current value from 100 mA to 50 mA in <i>Electrical Characteristics</i> table | 10 |
| • | Added OPA2625 data to Figure 12 | 13 |
| • | Added Figure 24 | 15 |
| • | Deleted "18" from several typical characteristic figure titles (typo) | 19 |

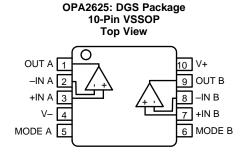
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5 Pin Configuration and Functions





Pin Functions: OPA625

| PIN | | 1/0 | DESCRIPTION | |
|------|----|-----|---|--|
| NAME | NO | 1/0 | DESCRIPTION | |
| +IN | 3 | I | Noninverting input | |
| -IN | 4 | 1 | Inverting input | |
| MODE | 5 | I | Controls OPA625 mode: V+ = low-power mode V- = high-drive mode NOTE: Do not float this pin. | |
| OUT | 1 | 0 | Output terminal | |
| V+ | 6 | | Positive supply voltage | |
| V- | 2 | _ | Negative supply voltage | |

Pin Functions: OPA2625

| PIN | | 1/0 | DECORIDATION | |
|--------|-----|-----|--|--|
| NAME | NO. | 1/0 | DESCRIPTION | |
| +IN A | 3 | I | Noninverting input for channel A | |
| −IN A | 2 | I | Inverting input for channel A | |
| +IN B | 7 | I | Noninverting input for channel B | |
| –IN B | 8 | I | Inverting input for channel B | |
| MODE A | 5 | 1 | Controls OPA2625 mode for channel A: V+ = low-power mode V- = high-drive mode NOTE: Do not float this pin. | |
| MODE B | 6 | 1 | Controls OPA2625 mode for channel B: V+ = low-power mode V- = high-drive mode NOTE: Do not float this pin. | |
| OUT A | 1 | 0 | Output terminal for channel A | |
| OUT B | 9 | 0 | Output terminal for channel B | |
| V+ | 10 | _ | Positive supply voltage | |
| V- | 4 | _ | Negative supply voltage | |

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | MAX | UNIT | |
|--------------------------------|---------------------------|------------|------------|------|--|
| Supply voltage, V _S | (V+) - (V-) | | 6 | V | |
| Input voltage ⁽²⁾ | +IN | (V-) - 0.3 | (V+) + 0.3 | | |
| | -IN | (V-) - 0.3 | (V+) + 0.3 | V | |
| | MODE | (V-) - 0.3 | (V+) + 0.3 | | |
| Output voltage | OUT | (V-) | (V+) | V | |
| | +IN | | 10 | | |
| | -IN | | 10 | A | |
| Sink current | MODE | | 10 | mA | |
| Sink current N | OUT | | 150 | | |
| | +IN | | 10 | | |
| Carrage arrange | -IN | | 10 | A | |
| Source current | MODE | | 10 | mA | |
| | OUT ⁽²⁾ | | 150 | | |
| T | Operating junction | -40 | 150 | 00 | |
| Temperature | Storage, T _{stg} | –65 | 150 | °C | |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|-------------|----------------------------|---|-------|------|
| V | Electrostatic | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±3000 | \/ |
| $V_{(ESD)}$ | discharge Charged-device m | Charged-device model (CDM), per JEDEC specification JESD22-C101 (2) | ±1500 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | NOM MAX | UNIT |
|----------------|---------------------------------|------|------|-------------|------|
| Vs | Supply input voltage, (V+) - (V | /–) | 2.7 | 5.5 | V |
| | | +IN | (V-) | (V+) - 1.15 | |
| V_{I} | Input voltage | -IN | (V-) | (V+) - 1.15 | V |
| | | MODE | (V-) | (V+) | |
| Vo | Output voltage | | (V–) | (V+) | V |
| Io | Output current | | -120 | 120 | mA |
| T _A | Operating free-air temperature |) | -40 | 125 | °C |
| TJ | Operating junction temperatur | e | -40 | 125 | °C |

Product Folder Links: OPA625 OPA2625

⁽²⁾ For input voltages beyond the power-supply rails, voltage or current must be limited.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information

| | | OPA625 | OPA2625 | |
|------------------------|--|-----------|-------------|------|
| | THERMAL METRIC ⁽¹⁾ | DBV (SOT) | DGS (VSSOP) | UNIT |
| | | 6 PINS | 10 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 184.9 | 171.7 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 123.6 | 68.4 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 30.7 | 91.9 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 22.1 | 9.4 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 30.2 | 90.5 | °C/W |
| R ₀ JC(bot) | Junction-to-case (bottom) thermal resistance | N/A | N/A | °C/W |

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics High-Drive Mode

at T_A = 25°C, V+ = 5 V, V- = 0 V, MODE pin connected to V- pin, V_{COM} = V_O = 2.5 V, gain (G) = 1, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)

| | PARAMETER | Т | EST CONDITIONS | MIN T | YP MAX | UNIT | |
|---------------------|---|--|---|-------|---------|--------------------|--|
| AC PER | FORMANCE | | | | | | |
| | Unity gain frequency | $V_O = 10 \text{ mV}_{PP}$ | | | 80 | MHz | |
| φ _m | Phase margin | | | | 50 | Degrees | |
| GBW | Gain-bandwidth product | $G = 100, V_O = 10 \text{ mV}_{PP}$ | | 1 | 120 | MHz | |
| CD. | Claurata | V _O = 1-V step, G = 1 | | | 45 | 1// | |
| SR | Slew rate | V _O = 4-V step, G = 2 | | 1 | 115 | V/µs | |
| | | | Settling time to 0.1% (10-bit accuracy) | | 80 | | |
| t _{settle} | Settling time | V _O = 4-V step, G = 2 | to 0.005% (14-bit accuracy) | 1 | 110 | ns | |
| | | | to 0.00153% (16-bit accuracy) | 2 | 280 | | |
| | Overshoot | V _O = 4-V step, G = 2 | | 2.5 | 5% | | |
| | Undershoot | V _O = 4-V step, G = 2 | | ; | 3% | | |
| | | | f = 10 kHz | 1 | 144 | | |
| HD2 | Second-order harmonic Distortion | $V_0 = 2 V_{PP}, G = 2$ | f = 100 kHz | 1 | 122 | dBc | |
| | | | f = 1 MHz | | 80 | | |
| | Third-order harmonic Distortion | | f = 10 kHz | 1 | 155 | | |
| HD3 | | $V_0 = 2 V_{PP}, G = 2$ | f = 100 kHz | 1 | 140 | dBc | |
| | | | f = 1 MHz | | 80 | | |
| | Second-order intermodulation distortion | V _O = 2 V _{PP} , f = 1 MHz, 200-kHz tone spacing | | | 90 | dBc | |
| | Third-order intermodulation distortion | V _O = 2 V _{PP} , f = 1 MHz, 200-kHz tone spacing | | 1 | 100 | dBc | |
| V _N | Input noise voltage | f = 0.1 Hz to 10 Hz, peak | -to-peak | (| 0.8 | μV_{PP} | |
| ٧N | input noise voitage | f = 0.1 Hz to 10 Hz, rms | | 1 | 120 | $\rm nV_{RMS}$ | |
| V_n | Input voltage noise | voltage noise f = 1 kHz | | ; | 3.2 | nV/√ Hz | |
| v _n | density | f = 10 kHz | | : | 2.5 | 110/ 1112 | |
| | Input current noise | f = 1 kHz | | | 4.1 | pA/√ Hz | |
| I _n | density | f = 10 kHz | | : | 2.8 | pAV VIIZ | |
| t _{OR} | Overload recovery time | G = 5 | G = 5 | | 50 | ns | |
| Z _o | Open-loop output impedance | f = 1 MHz | | | 1 | Ω | |
| | Crosstalk | DC | | 1 | 150 | dB | |
| | Olossiain | f = 1 MHz | | 1 | 127 | | |
| DC PER | FORMANCE | | | | | | |
| \/ | Input offset voltage | | | | 15 ±100 | \/ | |
| Vos | Input offset voltage | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | ±300 | μV | |



Electrical Characteristics High-Drive Mode (continued)

at T_A = 25°C, V+ = 5 V, V- = 0 V, MODE pin connected to V- pin, V_{COM} = V_O = 2.5 V, gain (G) = 1, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)

| | PARAMETER | TES | T CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--------------------------------|--|--|------------|-------------|----------------|----------|
| | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 0.5 | ±3 | μV/°C |
| dV _{OS} /dT | Input offset voltage drift | OPA2625 only, $T_A = -40$ °C t | o +125°C | | 0.6 | ±4 | |
| | Power-supply rejection | | | 100 | | | |
| PSRR | ratio | 2.7 V ≤ (V+) ≤ 5 V | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | 90 | 120 | | dB |
| | | | ^ | | 2 | 4 | |
| I _B | Input bias current | T _A = -40°C to +125°C | | | | 5.7 | μA |
| Ь | , | OPA2625 only, $T_A = -40^{\circ}C$ t | n +125°C | | | 6.5 | · |
| dl _B /dT | Input bias current drift | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | 5 · · · 25 · 5 | | 15 | 0.0 | nA/°C |
| а.в. а . | par side carreire anne | . A | | | 20 | 120 | |
| los | Input offset current | T _A = -40°C to +125°C | | | | 150 | nA |
| .08 | input onoct current | OPA2625 only, $T_A = -40^{\circ}$ C t | 0.+125°C | | | 200 | |
| dl _{OS} /dT | Input offset current drift | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | 0 +125 0 | | 0.6 | 200 | nA/°C |
| OPEN LO | | 1 _A = -40 C to +123 C | | | 0.0 | | TIA/ C |
| OPEN LO | OF GAIN | (//) + () 2) / + () + () / () () | 2 V B - 600 O | 110 | | | |
| | | $(V-) + 0.2 V < V_O < (V+) - 0.$ | | | | | |
| | | $(V-) + 0.15 V < V_O < (V+) - 0.15 V < V_O < (V+) = 0.15 V < 0.15$ | 1 | 114 | | | |
| A _{OL} | Open-loop gain | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | $(V-) + 0.2 V < V_O < (V+) - 0.2 V,$ $R_{LOAD} = 600 \Omega$ | 106 | 128 | | dB |
| | | ^ | $(V-) + 0.15 V < V_O < (V+) - 0.15 V$, $R_{LOAD} = 10 k\Omega$ | 110 | 132 | | |
| INPUT VO | DLTAGE | | | | | | |
| V_{CM} | Common-mode voltage range | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | (V-) | | (V+) – 1.15 | V |
| OMDD | Common-mode rejection | ()() ()() (4.45)(| | 100 | 117 | | -ID |
| CMRR | ratio | $(V-) < V_{COM} < (V+) - 1.15 V$ | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | 90 | 115 | | dB |
| INPUT IM | PEDANCE | | | | | | |
| Z _{ID} | Differential input impedance | | | | 27 1.2 | | KΩ pF |
| Z _{IC} | Common-mode input impedance | | | | 47 1.5 | | MΩ pF |
| OUTPUT | | | | 1 | | | |
| | | | | | 60 | 80 | |
| | Output voltage swing to | $R_{LOAD} = 600 \Omega$ | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 100 | |
| | the rail | | | | 20 | 35 | mV |
| | | $R_{LOAD} = 10 \text{ k}\Omega$ | $T_{\Delta} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 40 | |
| I _{sc} | Short-circuit current | | 1 | | 150 | | mA |
| C _{LOAD} | Capacitive load drive | | | See Typi | cal Charact | eristics | |
| MODE | | | | 71- | | - | <u> </u> |
| V _{IL} | High-drive (HD) mode threshold | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | (V-) | | (V-) + 0.5 | V |
| V _{IH} | Low-power (LP) mode threshold | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | (V-) + 1.2 | | (V+) | V |
| I _{IL} | Low-level input current | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, V_{MOD}$ | _E ≤ (V–) + 0.5 V | | 0.01 | 1 | μA |
| | · | $T_A = -40$ °C to +125°C, V_{MOD} | | | 20 | 30 | r |
| I _{IH} | High-level input current | | o +125°C, V _{MODE} ≥ (V–) + 1.2 V | | - | 1 | μA |
| POWER S | SUPPLY | | | | | | |
| | Quiescent current per | $I_O = 0 \text{ mA},$ | | | 2 | 2.2 | mA |
| lα | amplifier · | MODE connected to ground | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 3.1 | IIIA |



6.6 Electrical Characteristics Low-Power Mode

at T_A = 25°C, V+ = 5 V, V- = 0 V, V_{MODE} = 5 V, V_{COM} = V_O = 2.5 V, gain (G) = 1, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)

| | PARAMETER | TES. | T CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------|----------------------------|--|---|------|-----|----------------|-------------|
| AC PERF | FORMANCE | | , | | | | |
| GBW | Gain-bandwidth product | $G = 100, V_O = 10 \text{ mV}_{PP}$ | | | 1 | | MHz |
| φ _m | Phase margin | | | | 72 | | Degrees |
| 0.0 | 01 . | V _O = 1-V step | | | 4.3 | | N // |
| SR | Slew rate | V _O = 4-V step, G = 2 | | | 4.1 | | V/µs |
| Z _o | Open-loop output impedance | f = 1 MHz | = 1 MHz | | 12 | | Ω |
| DC PERF | FORMANCE | • | • | | | | |
| · · · | Innut offeet valtage | | | | 0.6 | 3 | mV |
| V _{OS} | Input offset voltage | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 0.7 | 3.7 | mv |
| DCDD | Power-supply rejection | 271/2/11/251/ | | 74 | | | 4D |
| PSRR | ratio | 2.7 V ≤ (V+) ≤ 5 V | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | 70 | 100 | | dB |
| | Input bias current | | | | | 150 | |
| I _B | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 140 | 200 | nA |
| | | OPA2625 only, $T_A = -40$ °C to | | | 250 | | |
| | 1 | | | | | 20 | nA |
| los | Input offset current | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 25 | | |
| OPEN LO | OOP GAIN | 1 | , | | | ' | |
| ^ | On an Inna ania | $T_A = -40$ °C to +125°C | $(V-) + 0.2 V < V_O < (V+) - 0.2 V,$ $R_{LOAD} = 600 \Omega$ | 70 | 100 | | dB |
| A _{OL} | Open-loop gain | | $(V-) + 0.15 V < V_O < (V+) - 0.15 V,$ $R_{LOAD} = 10 k\Omega$ | 90 | 100 | | |
| INPUT V | OLTAGE | | | | | | |
| V_{CM} | Common-mode voltage range | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | (V-) | | (V+) – 1.15 | V |
| CMRR | Common-mode rejection | (V-) < V _{COM} < (V+) - 1.15 V | | 66 | 114 | | dB |
| CIVIKK | ratio | $(V-) < V_{COM} < (V+) - 1.15 V$ | $T_A = -40^{\circ}C \text{ to } +125^{\circ}C$ | 60 | 114 | | uБ |
| OUTPUT | | • | • | | | | |
| | Output voltage swing to | T 4000 to 140500 | $R_{LOAD} = 600 \Omega$ | | | 110 | \/ |
| | the rail | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | $R_{LOAD} = 10 \text{ k}\Omega$ | | | 40 | mV |
| I _{sc} | Short-circuit current | | | | 100 | | mA |
| POWER : | SUPPLY | | · | | | ' | |
| | Quiescent current per | $I_{O} = 0 \text{ mA},$ | | | 270 | 320 | |
| IQ | amplifier | MODE connected to V+ | $T_A = -40$ °C to +125°C | | | 450 | μΑ |

Product Folder Links: OPA625 OPA2625



6.7 Electrical Characteristics High-Drive Mode

at T_A = +25°C, V+ = 2.7 V, V- = 0 V, V_{MODE} = 0 V, V_{COM} = V_O = 1.35 V, gain (G) = 1, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 1 k Ω connected to 1.35 V (unless otherwise noted)

| | PARAMETER | TE | ST CONDITIONS | MIN | TYP | MAX | UNIT | |
|----------------------|--|---|--------------------------------|-----|-----|--------------|---------|--|
| AC PERF | ORMANCE | | | | | | | |
| | Unity gain frequency | $V_O = 10 \text{ mV}_{PP}$ | | | 76 | | MHz | |
| φ _m | Phase margin | | | | 45 | | Degrees | |
| GBW | Gain-bandwidth product | G = 100, V _O = 10 mV _{PP} | | 120 | | MHz | | |
| SR | Slew rate | V _O = 1-V step, G = 2 | | 45 | | V/µs | | |
| | | | to 0.1% | | 80 | | | |
| t _{settle} | Settling time | V _O = 1-V step, G = 2 | to 0.01% | | 170 | | ns | |
| | ŭ | 0 | to 0.000763% (17-bit accuracy) | | 250 | | | |
| | Overshoot | V _O = 1-V step, G = 2 | | | 6% | | | |
| | Undershoot | V _O = 1-V step, G = 2 | | | 5% | | | |
| | | (V+) = 3.3 V, (V-) = 0 V, | f = 10 kHz | | 136 | | | |
| HD2 | Second order harmonic Distortion | $V_{COM} = 1.1 \text{ V},$ | f = 100 kHz | | 118 | | dBc | |
| | Distortion | $V_O = 2 V_{PP}$ | f = 1 MHz | | 80 | | | |
| | | | f = 10 kHz | | 143 | | | |
| | | | OPA2625 only, f = 10 kHz | | 143 | | ı | |
| | Third order harmonic | (V+) = 3.3 V, (V-) = 0 V, | f = 100 kHz | | 130 | | | |
| HD3 | Distortion | $V_{COM} = 1.1 \text{ V},$ $V_{O} = 2 \text{ V}_{PP}$ | OPA2625 only, f = 100 kHz | | 125 | | dBc | |
| | | | f = 1 MHz | | 85 | | | |
| | | | OPA2625 only, f = 1 MHz | | 74 | | | |
| | Second order inter- modulation distortion | $(V+) = 3.3 \text{ V}, (V-) = 0 \text{ V}, V_{COM} = 1.1 \text{ V}, V_{O} = 2 \text{ V}_{PP},$ f = 1 MHz, 200-kHz tone spacing | | | 95 | | dBc | |
| | Third order inter- modulation distortion | $(V+) = 3.3 \text{ V}, (V-) = 0 \text{ V}, V_{COM} = 1.1 \text{V}, V_{O} = 1 \text{ V}_{PP},$ f = 1 MHz, 200-kHz tone spacing | | | 104 | | dBc | |
| V _N | Input noise voltage | f = 0.1 Hz to 10 Hz peak to | | 0.8 | | μV_{PP} | | |
| | | f = 0.1 Hz to 10 Hz rms | | 120 | | nV_{RMS} | | |
| V _n | Input voltage noise density | f = 10 kHz | | | 2.5 | | nV/√Hz | |
| I _n | Input current noise density | f = 10 kHz | | | 2.8 | | pA/√Hz | |
| t _{OR} | Overload recovery time | G = 5 | | | 35 | | ns | |
| Z _o | Open-loop output impedance | f = 1 MHz | | | 1.3 | | Ω | |
| | 0 | DC f = 1 MHz | | | 150 | | -ID | |
| | Crosstalk | | | | 127 | | dB | |
| DC PERF | ORMANCE | | | | | | | |
| V | Input offset voltage | | | | 15 | ±100 | / | |
| Vos | input onset voltage | $T_A = -40$ °C to +125°C | | | | ±300 | μV | |
| 4)/ /4T | Input offset voltage drift | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ OPA2625 only, $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 0.5 | ±3.1 | \.//00 | |
| dV _{OS} /dT | | | | | 0.6 | ±4 | μV/°C | |
| I _B | Input bias current | current $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ $OPA2625 \text{ only, } T_A = -40^{\circ}\text{C to } +125^{\circ}$ | | | 2 | 4 | | |
| | | | | | | 5.7 | μΑ | |
| | | | | | | 6.5 | | |
| dl _B /dT | Input bias current drift | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 15 | | nA/°C | |
| | | | | | 20 | 120 | | |
| Ios | Input offset current | $T_A = -40$ °C to +125°C | | | | 150 | nA | |
| | • | OPA2625 only, T _A = -40°C | | | 200 | | | |
| dl _{OS} /dT | Input offset current drift | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 80 | | pA/°C | |
| OPENLIO | OP GAIN | | | • | | | | |

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Electrical Characteristics High-Drive Mode (continued)

at T_A = +25°C, V+ = 2.7 V, V- = 0 V, V_{MODE} = 0 V, V_{COM} = V_O = 1.35 V, gain (G) = 1, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 1 k Ω connected to 1.35 V (unless otherwise noted)

| | PARAMETER | TES | CONDITIONS | MIN | TYP | MAX | UNIT |
|---|--|--|---|-----------------------------|-----------|----------------|-------------------|
| | Open-loop gain | $\begin{aligned} &(V-) + 0.2 \ V < V_O < (V+) - 0.2 \ V, \\ &R_{LOAD} = 600 \ \Omega \\ &(V-) + 0.15 \ V < V_O < (V+) - 0.15 \ V, \\ &R_{LOAD} = 10 \ k\Omega \end{aligned}$ | | 110 | | | |
| A _{OL} | | | | 114 | | | 15 |
| | | $T_A = -40$ °C to +125°C | $(V-) + 0.2 V < V_O < (V+) - 0.2 V,$ $R_{LOAD} = 600 \Omega$ | 106 | 128 | | dB |
| | | | $(V-) + 0.15 V < V_O < (V+) - 0.15 V,$ $R_{LOAD} = 10 k\Omega$ | 110 | 132 | | † |
| INPUT V | OLTAGE | | | | | | |
| V_{CM} Common-mode voltage $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | | (V-) | | (V+) – 1.15 | V |
| CMRR | Common-mode rejection | (V-) < V _{COM} < (V+) - 1.15 V | | 100 | 117 | | dB |
| CIVINN | ratio | $(V-) < V_{COM} < (V+) - 1.15 V$ | $T_A = -40^{\circ}C \text{ to } +125^{\circ}C$ | 90 | 115 | | иь |
| INPUT IN | IPEDANCE | T | | | | | |
| Z_{ID} | Differential input impedance | | | | 27 0.8 | | $KΩ \parallel pF$ |
| Z _{IC} | Common-mode input impedance | | | | 47 1.2 | | MΩ pF |
| OUTPUT | | | | | | | |
| | | B - 600 O | | | 60 | 80 | |
| | Output voltage swing to the rail $R_{LOAD} = 600 \Omega$ $R_{LOAD} = 10 \text{ k}\Omega$ | Utput voltage swing to $T_A = -40$ °C to +125 e rail | $T_A = -40^{\circ}C \text{ to } +125^{\circ}C$ | | | 100 | mV |
| | | | | | 20 | 35 | IIIV |
| | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 40 | | |
| I _{SC} | Short-circuit current | | | | 80 | | mA |
| C_{LOAD} | Capacitive load drive | | | See Typical Characteristics | | | |
| MODE | | | | | | | |
| V_{IL} | High-drive (HD) mode threshold | T _A = -40°C to +125°C | | (V-) | | (V-) + 0.5 | V |
| V_{IH} | Low-power (LP) mode threshold | $T_A = -40$ °C to +125°C | | (V-) + 1.2 | | (V+) | V |
| POWER : | SUPPLY | | | | | | |
| 1 | Quiescent current per | $I_O = 0 \text{ mA}$ | | | 2 | 2.1 | mΛ |
| IQ | amplifier | MODE connected to ground | T _A = -40°C to +125°C | | | 2.8 | mA |

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6.8 Electrical Characteristics Low-Power Mode

at T_A = +25°C, V+ = 2.7 V, V- = 0 V, V_{MODE} = 2.7 V, V_{COM} = V_O = 1.35V, gain (G) = 1, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 1 k Ω connected to 1.35 V (unless otherwise noted)

| | PARAMETER | TES | r conditions | MIN | TYP | MAX | UNIT | |
|--------------------------------------|----------------------------|---|---|------|-----|-------------------|---------|----|
| AC PER | FORMANCE | | , | | | | | |
| GBW | Gain-bandwidth product | G = 100, V _{IN} = 10 mV _{PP} | | 0.8 | | MHz | | |
| φ _m | Phase margin | | | | 72 | | Degrees | |
| SR | Slew rate | V _O = 1 V-step, G = 2 | | | 3.7 | | V/µs | |
| Z _o | Open-loop output impedance | f = 1 MHz | | | 13 | | Ω | |
| DC PER | FORMANCE | | | | | | | |
| Vos | Input offset voltage | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 0.6 | 3 ±3.6 | | |
| | | T _A = -40°C t0 +125°C | | | 0.7 | | | |
| | Input bias current | T _A = -40°C to +125°C | | | 140 | 150 140 220 nA | | |
| l _B | input bias current | OPA2625 only, $T_A = -40^{\circ}\text{C to}$ | 2 ±125° | | 140 | 250 | ΠA | |
| | | OF A2023 Offly, 1 _A = -40 C to | J +125 | | 200 | | | |
| I _{OS} Input offset current | | T _A = -40°C to +125°C | | | | 25 | nA | |
| OPEN LOOP GAIN | | | | | | 20 | | |
| A _{OL} | Open-loop gain | | $(V-) + 0.2 V < V_O < (V+) - 0.2 V,$ $R_{LOAD} = 600 \Omega$ | 74 | 100 | | | |
| | | Open-loop gain $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | $(V-) + 0.15 V < V_O < (V+) - 0.15 V,$ $R_{LOAD} = 10 k\Omega$ | 84 | 100 | | dB | |
| INPUT V | OLTAGE | | | | | • | | |
| V _{CM} | Common-mode voltage range | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | (V-) | | (V+) – 1.15 | V | |
| OMBB | Common-mode rejection | Common-mode rejection | 0/) // 0/) 4.45 // | | 66 | 114 | | 15 |
| CMRR | ratio | $(V-) < V_{COM} < (V+) - 1.15 V$ | T _A = -40°C to +125°C | 60 | 114 | | dB | |
| OUTPUT | Ī | | | | | | | |
| | Output voltage swing to | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | R _{LOAD} = 600 Ω | | | 110 | \/ | |
| | rail | | $R_{LOAD} = 10 \text{ k}\Omega$ | | | 40 | mV | |
| I _{sc} | Short-circuit current | | | | 50 | | mA | |
| POWER | SUPPLY | | <u> </u> | | | <u>'</u> | | |
| | Quiescent current per | I _O = 0 mA, MODE connected to V+ | | | 250 | 270 | | |
| IQ | amplifier | | $T_A = -40$ °C to +125°C | | | 400 | μΑ | |

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6.9 Switching Characteristics

at $T_A = 25$ °C, $V_{+} = 5$ V, $V_{-} = 0$ V, MODE pin connected to V_{-} pin, gain (G) = 1 , $V_{COM} = V_{O} = 2.5$ V, $C_{LOAD} = 20$ pF, and $R_{LOAD} = 1$ k Ω connected to 2.5 V (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------|--|---|-----|-----|-----|------|
| t _{LP-HD} | | Settling time to within 50 μ V of final value, MODE pin = high to low (LP to HD), V _O = 3.8 V | | 180 | | ns |
| | Delay time, MODE pin falling (low-power mode to high-drive mode) | t _{LP-HD} is defined as the time taken for the quiescent current to increase from 110% of its value in LP mode to 90% of its value in HD mode. | | 170 | | ns |
| t _{HD-LP} | Delay time, MODE pin rising (high-drive mode to low-power mode) | t _{HD-LP} is defined as the time taken for the quiescent current to decrease from 90% of its value in HD mode to 110% of its value in LP mode. | | 300 | | ns |

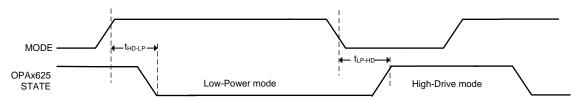
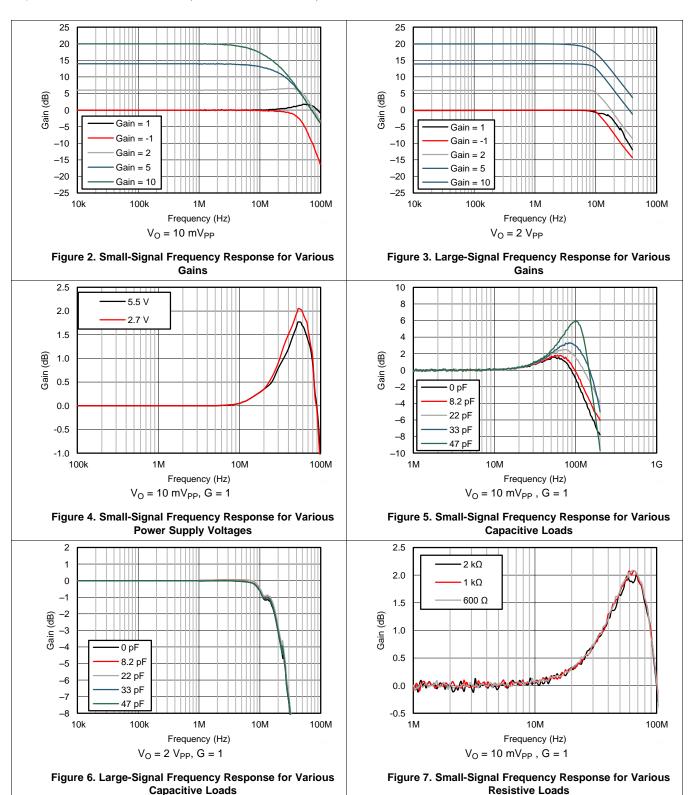


Figure 1. Switching Characteristics Timing Diagram

TEXAS INSTRUMENTS

6.10 Typical Characteristics

At T_A = 25°C, V+ = 5 V, V- = 0 V, MODE = V-, V_{COM} = V_O = 2.5 V, gain (G) = 2, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)





At T_A = 25°C, V+ = 5 V, V- = 0 V, MODE = V-, V_{COM} = V_O = 2.5 V, gain (G) = 2, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)

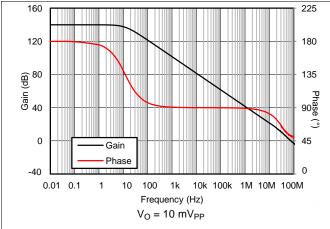


Figure 8. High-Drive Mode Open-Loop Gain and Phase vs Frequency

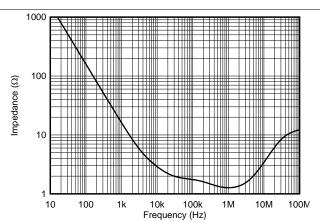


Figure 9. High-Drive Mode Open-Loop Output Impedance vs Frequency

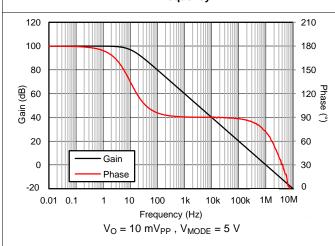


Figure 10. Low-Power Mode Open-Loop Gain and Phase vs Frequency

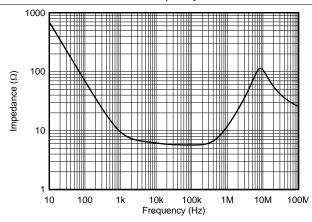


Figure 11. Low-Power Mode Open-Loop Output Impedance vs Frequency

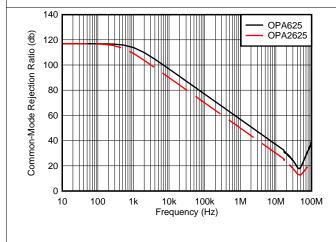


Figure 12. Common-Mode Rejection Ratio vs Frequency

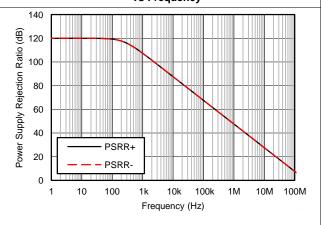
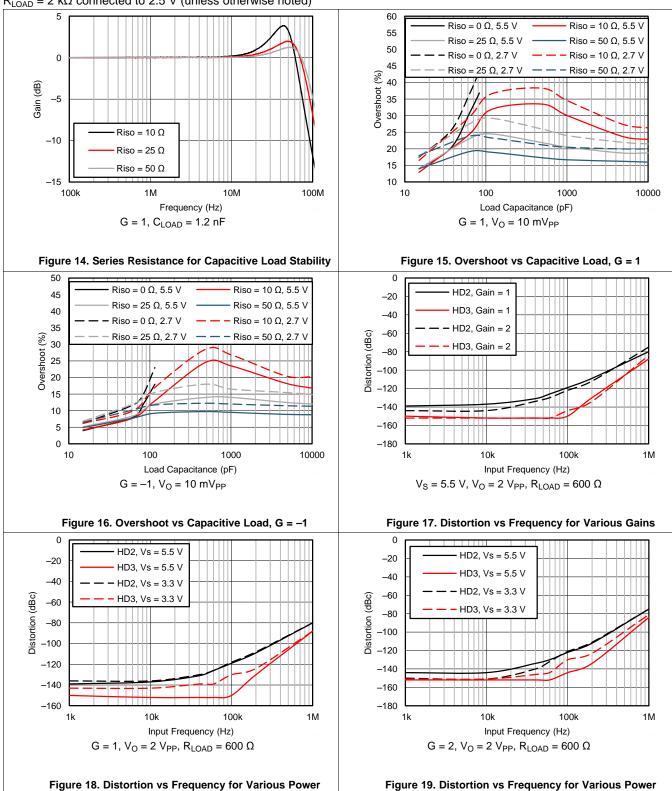


Figure 13. Power-Supply Rejection Ratio vs Frequency



At $T_A = 25$ °C, V+ = 5 V, V- = 0 V, MODE = V-, $V_{COM} = V_O = 2.5$ V, gain (G) = 2, $R_F = 1$ k Ω , $C_F = 2.7$ pF, $C_{LOAD} = 20$ pF, and $R_{LOAD} = 2$ k Ω connected to 2.5 V (unless otherwise noted)



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Supplies

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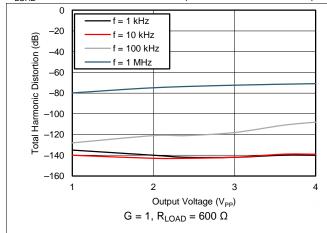
Supplies



At T_A = 25°C, V+ = 5 V, V- = 0 V, MODE = V-, V_{COM} = V_O = 2.5 V, gain (G) = 2, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)

0

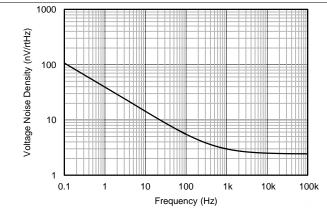
2 kΩ



 $\frac{1}{9}$ $\frac{1}{1}$ $\frac{1$

Figure 20. Total Harmonic Distortion vs Output Voltage for Various Frequencies

Figure 21. Total Harmonic Distortion vs Frequency for Various Loads



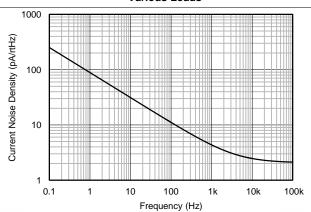
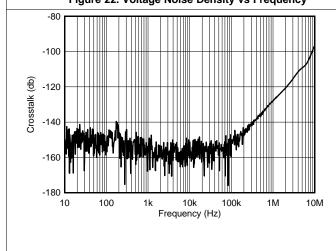


Figure 22. Voltage Noise Density vs Frequency

Figure 23. Current Noise Density vs Frequency



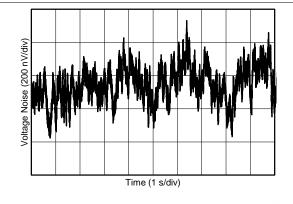
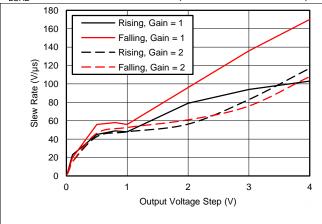


Figure 24. Crosstalk vs Frequency

Figure 25. 0.1-Hz to 10-Hz Voltage Noise



At T_A = 25°C, V+ = 5 V, V- = 0 V, MODE = V-, V_{COM} = V_O = 2.5 V, gain (G) = 2, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)



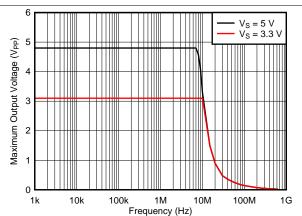
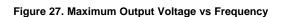
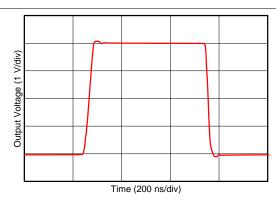
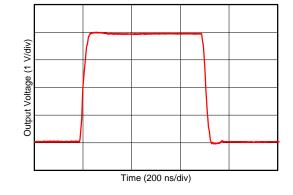


Figure 26. Slew Rate vs Output Step Size





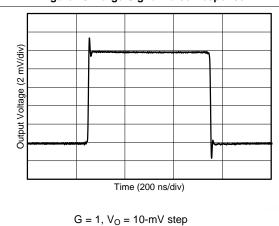


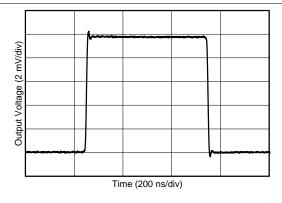
$$G = 1$$
, $V_O = 4$ -V step

 $G = -1, V_O = 4-V \text{ step}$



Figure 29. Large-Signal Pulse Response





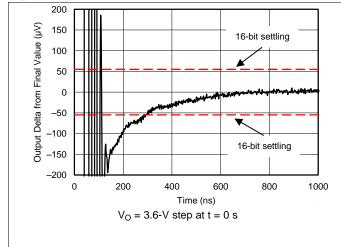
G = -1, $V_O = 10$ -mV step

Figure 30. Small-Signal Pulse Response

Figure 31. Small-Signal Pulse Response



At $T_A = 25^{\circ}C$, $V_{+} = 5$ V, $V_{-} = 0$ V, $MODE = V_{-}$, $V_{COM} = V_{O} = 2.5$ V, gain (G) = 2, $R_F = 1$ k Ω , $C_F = 2.7$ pF, $C_{LOAD} = 20$ pF, and $R_{LOAD} = 2 \text{ k}\Omega$ connected to 2.5 V (unless otherwise noted)



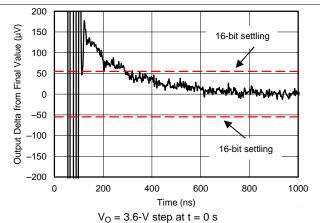
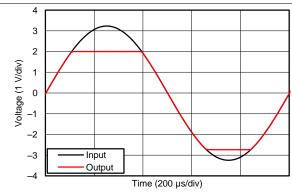
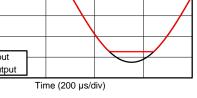
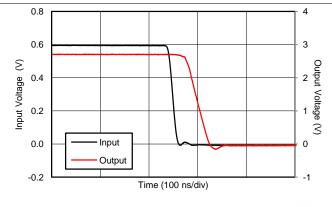


Figure 32. 16-Bit Negative Settling Time

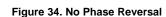




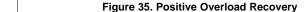


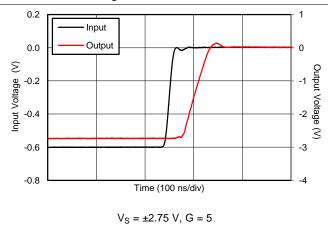


$$V_S = \pm 2.75 \ V, \ G = 5$$



 $V_S = \pm 2.75 V, G = 1$





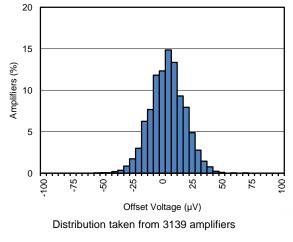
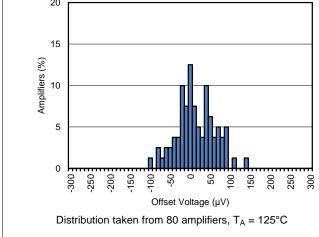


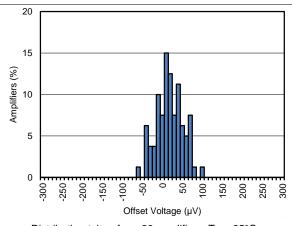
Figure 36. Negative Overload Recovery

Figure 37. Input Offset Voltage Distribution

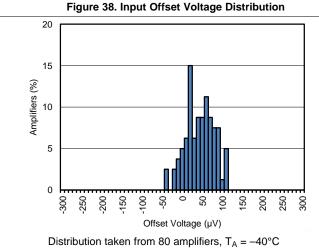


At $T_A = 25$ °C, $V_{+} = 5$ V, $V_{-} = 0$ V, $MODE = V_{-}$, $V_{COM} = V_{O} = 2.5$ V, gain (G) = 2, $R_F = 1$ k Ω , $C_F = 2.7$ pF, $C_{LOAD} = 20$ pF, and $R_{LOAD} = 2 \text{ k}\Omega$ connected to 2.5 V (unless otherwise noted)





Distribution taken from 80 amplifiers, T_A = 85°C



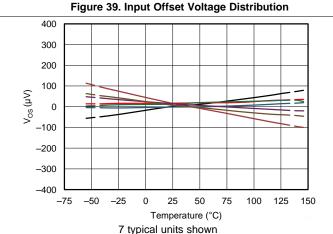


Figure 41. Input Offset Voltage vs Temperature

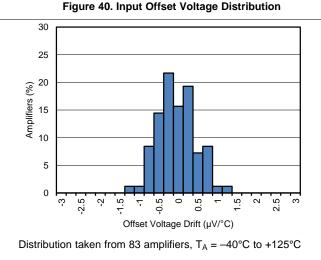


Figure 42. Input Offset Voltage Drift Distribution

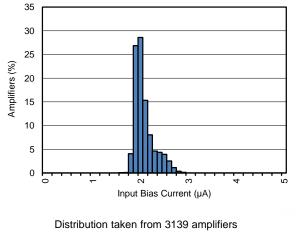


Figure 43. Input Bias Current Distribution

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At T_A = 25°C, V+ = 5 V, V- = 0 V, MODE = V-, V_{COM} = V_O = 2.5 V, gain (G) = 2, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)

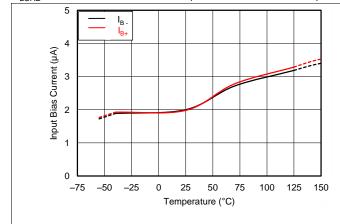
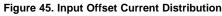
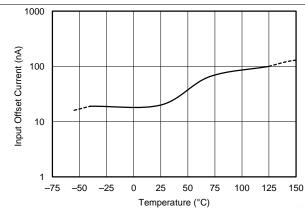


Figure 44. Input Bias Current vs Temperature





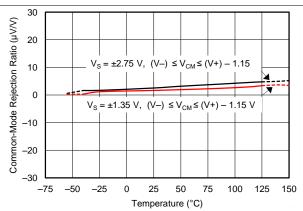
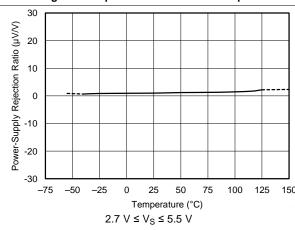


Figure 46. Input Offset Current vs Temperature

Figure 47. Common-Mode Rejection Ratio vs Temperature



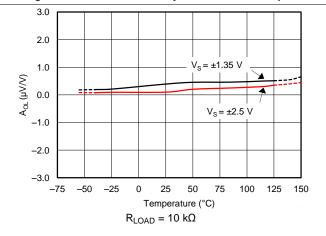


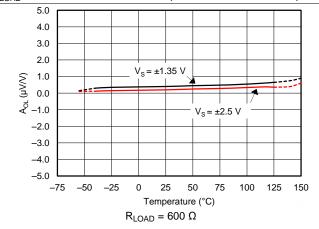
Figure 48. Power-Supply Rejection Ratio vs Temperature

Figure 49. Open-Loop Gain vs Temperature with 10-k Ω Load

TEXAS INSTRUMENTS

Typical Characteristics (continued)

At $T_A = 25$ °C, V+ = 5 V, V- = 0 V, MODE = V-, $V_{COM} = V_O = 2.5$ V, gain (G) = 2, $R_F = 1$ k Ω , $C_F = 2.7$ pF, $C_{LOAD} = 20$ pF, and $R_{LOAD} = 2$ k Ω connected to 2.5 V (unless otherwise noted)



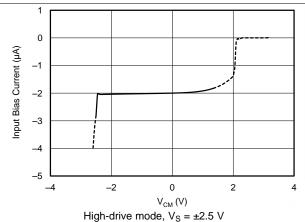
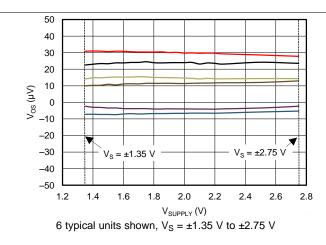


Figure 50. Open-Loop Gain vs Temperature with $600-\Omega$ Load

Figure 51. Input Bias Current vs Input Common-Mode Voltage



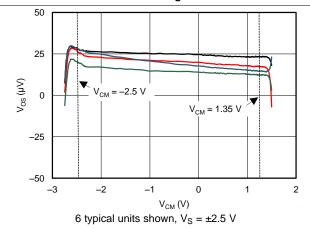
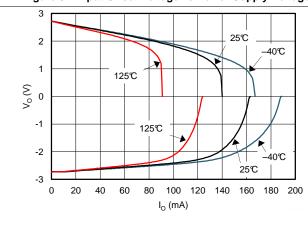


Figure 52. Input Offset Voltage vs Power-Supply Voltage

Figure 53. Input Offset Voltage vs Common-Mode Voltage



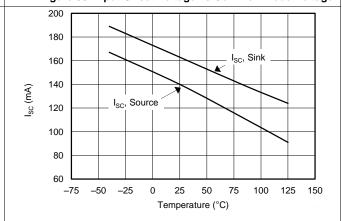
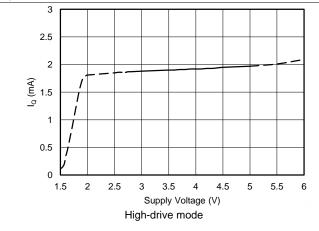


Figure 54. Output Voltage vs Output Current

Figure 55. Short-Circuit Current vs Temperature



At T_A = 25°C, V+ = 5 V, V- = 0 V, MODE = V-, V_{COM} = V_O = 2.5 V, gain (G) = 2, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)



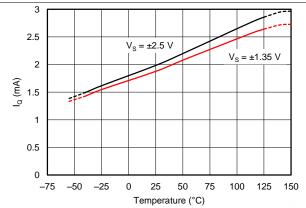
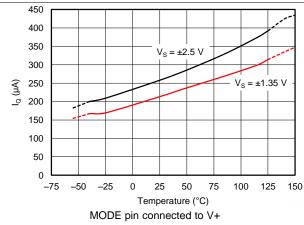


Figure 56. High-Drive Mode Quiescent Current vs Power-Supply Voltage

Figure 57. High-Drive Mode Quiescent Current vs
Temperature



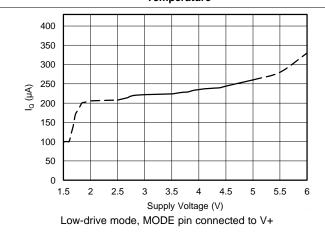
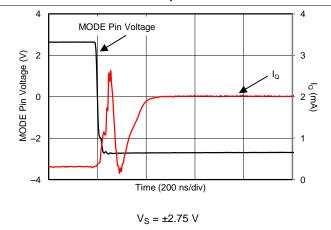


Figure 58. Low-Power Mode Quiescent Current vs
Temperature

Figure 59. Low-Power Mode Quiescent Current vs Power-Supply Voltage



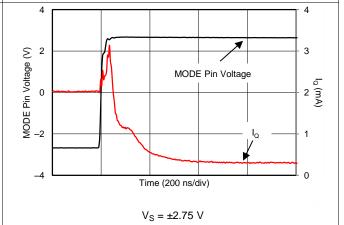


Figure 60. Quiescent Current When MODE transitions From High To Low

Figure 61. Quiescent Current When MODE Transitions From Low To High



At T_A = 25°C, V+ = 5 V, V- = 0 V, MODE = V-, V_{COM} = V_O = 2.5 V, gain (G) = 2, R_F = 1 k Ω , C_F = 2.7 pF, C_{LOAD} = 20 pF, and R_{LOAD} = 2 k Ω connected to 2.5 V (unless otherwise noted)

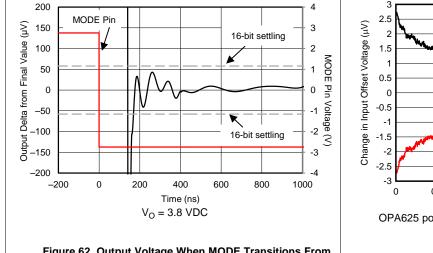


Figure 62. Output Voltage When MODE Transitions From High To Low

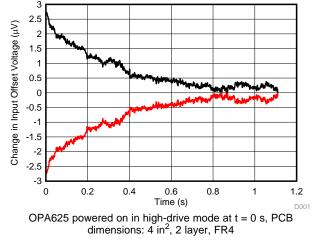


Figure 63. Warm-Up Time

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7 Parameter Measurement Information

7.1 DC Parameter Measurements

The circuit shown in Figure 64 is used to measure the dc input offset related parameters of the OPAx625. Input offset voltage, power supply rejection ratio, common mode rejection ratio and open loop gain can be measured with this circuit. The basic test procedure requires setting the inputs (the power-supply voltage, V_S , and the common-mode voltage, V_{CM}), to the desired values. V_O is set to the desired value by adjusting the loop-drive voltage while measuring V_O . After all inputs are configured, measure the input offset at the V_X measurement point. Calculate the input offset voltage by dividing the measured result by 101. Changing the voltages on the various inputs changes the input offset voltage. The input parameters can be measured according to the relationships illustrated in Equation 1 through Equation 5.

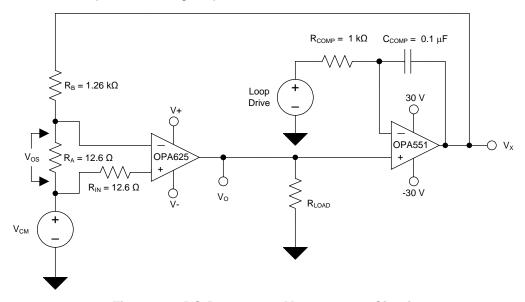


Figure 64. DC-Parameters Measurement Circuit

$$V_{OS} = \frac{V_X}{101} \tag{1}$$

$$V_{OSDrift} = \frac{\Delta V_{OS}}{\Delta Temperature}$$
 (2)

$$PSRR = \frac{\Delta V_{OS}}{\Delta V_{SUPPLY}}$$
(3)

$$CMRR = \frac{\Delta V_{OS}}{\Delta V_{CM}}$$
(4)

$$AOL = \frac{\Delta V_{O}}{\Delta V_{OS}}$$
 (5)



7.2 Transient Parameter Measurements

The circuit shown in Figure 65 is used to measure the transient response of the OPAx625. Configure V+, V–, R_{ISO} , R_{LOAD} , and C_{LOAD} as desired. Monitor the input and output voltages on an oscilloscope or other signal analyzer. Use this circuit to measure large-signal and small-signal transient response, slew rate, overshoot, and capacitive-load stability.

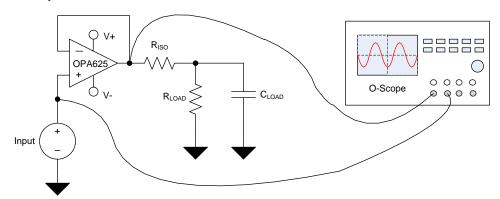


Figure 65. Pulse-Response Measurement Circuit

7.3 AC Parameter Measurements

The circuit shown in Figure 66 is used to measure the ac parameters of the OPAx625. Configure V+, V-, and C_{LOAD} as desired. The THS4271 are used to buffer the input and output of the OPAx625 to prevent loading by the gain phase analyzer. Monitor the input and output voltages on a gain phase analyzer. Use this circuit to measure the gain bandwidth product, and open-loop gain versus frequency versus capacitive load.

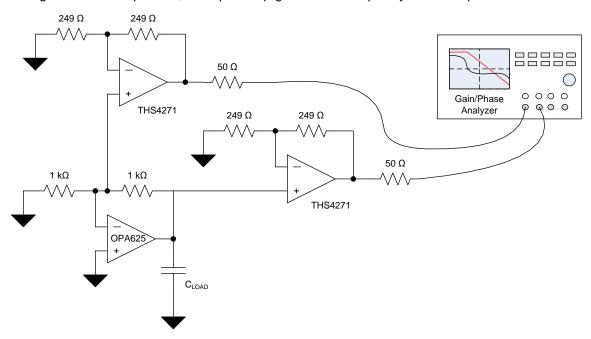


Figure 66. AC-Parameters Measurement Circuit



7.4 Noise Parameter Measurements

The circuit shown in Figure 67 is used to measure the voltage noise of the OPAx625. Configure V+, V-, and C_{LOAD} as desired.

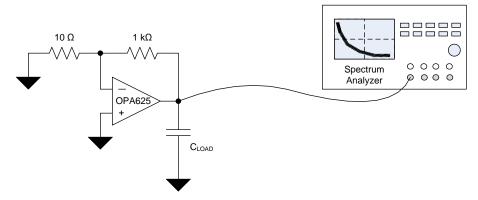


Figure 67. Voltage Noise Measurement Circuit

The circuit shown in Figure 68 is used to measure the current noise of the OPAx625. Configure V+, V- and C_{LOAD} as desired.

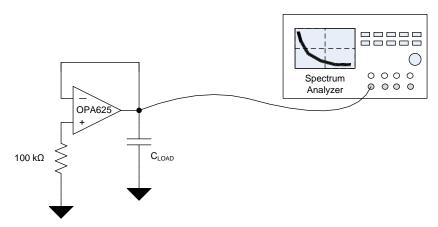


Figure 68. Current Noise Measurement Circuit

The circuit shown in Figure 69 is used to measure the OPAx625 0.1-Hz to 10-Hz voltage noise. Configure V+, V-, and C_{LOAD} as desired.

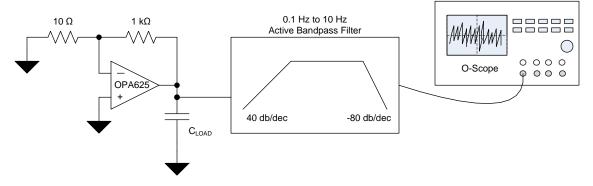


Figure 69. 0.1-Hz to 10-Hz Voltage-Noise Measurement Circuit

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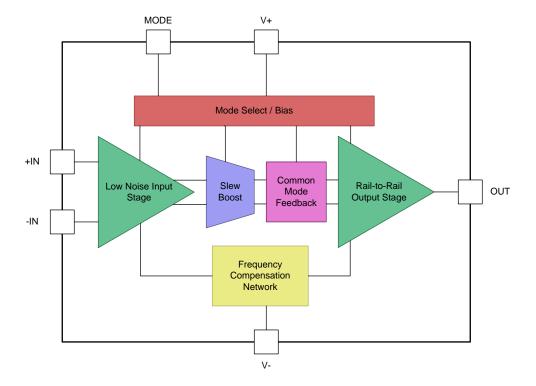


8 Detailed Description

8.1 Overview

The OPAx625 is a fast-settling, high slew rate, high-bandwidth, voltage-feedback operational amplifier. Low offset and low offset drift combine with the superior dynamic performance and very low output impedance, resulting in an amplifier suited for driving 16-bit SAR ADCs, and buffering precision voltage references in industrial applications. The OPAx625 is comprised of a low-noise input stage, a slew boost stage, and a rail-to-rail output stage. A mode bias select feature allows the OPAx625 to be configured in a high-drive mode and a low-power mode. High-drive mode is used when driving SAR ADCs during the ADC signal acquisition period. The OPAx625 is also configurable in low-power mode while the SAR ADC is converting the acquired signal, thus saving overall system power. To facilitate a fast transition from low-power mode to high-drive mode, the OPAx625 does not completely shut down while in low-power mode; rather, the device remains as an active amplifier with a lower bandwidth (1 MHz) and relaxed dc specifications.

8.2 Functional Block Diagram





8.3 Feature Description

8.3.1 SAR ADC Driver

The OPAx625 is designed to drive precision (16-bit and 18-bit) SAR ADCs at sample rates up to 1 MSPS. The combination of low output impedance, low THD, low noise, and fast settling time make the OPAx625 the ideal choice for driving both the SAR ADC inputs, as well as the reference input to the ADC. Internal slew boost circuitry increases the slew rate as a function of the input signal magnitude, resulting in settling from a 4-V step input to 16-bit levels within 280 ns. Low output impedance (1 Ω at 1 MHz) ensures capacitive load stability with minimal overshoot.

8.3.2 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress (EOS). These questions tend to focus on the device inputs, but may involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly. Having a good understanding of this basic ESD circuitry and its relevance to an electrical overstress event is helpful. See Figure 70 for an illustration of the ESD circuits contained in the OPAx625. The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where the diodes meet at an absorption device or the power-supply ESD cell, internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.

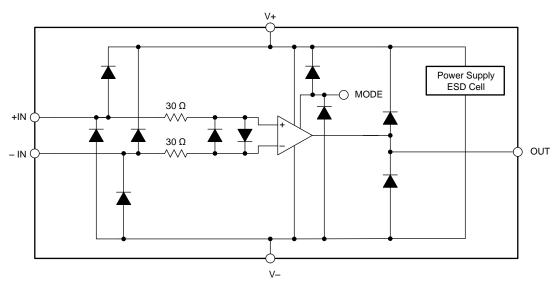


Figure 70. Simplified ESD Circuit



8.4 Device Functional Modes

The OPAx625 has two functional modes: high-drive and low-power. In low-power mode, the quiescent current of the OPAx625 is reduced to 270 μ A (typ), and results in significantly lower bandwidth, higher noise, and lower output current drive. The OPAx625 transitions from low-power mode to high-drive mode in 170 ns.

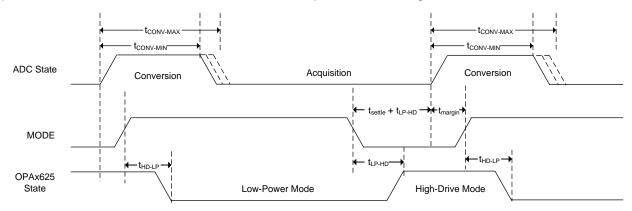


Figure 71. Simplified Timing Diagram: Power-Scaling Precision Signal Chain

8.4.1 High-Drive Mode

Place the OPAx625 into high-drive mode by applying a logic level low to the MODE pin. The MODE pin can be driven by a general-purpose input/output (GPIO) from the system controller, from discrete logic gates, or can be connected directly to the V- pin. Do not leave the MODE pin floating. When driving the MODE pin from a microcontroller GPIO, make sure that the GPIO is not placed into a high-impedance state. Placing the GPIO into a high impedance state results in the MODE pin essentially floating, and is not recommended. Do not drive the MODE pin voltage below the voltage at the V- pin; see the Absolute Maximum Ratings for the allowable voltage to drive the MODE pin. Use the MODE pin to force the OPAx625 in either the high-drive mode or the low-power mode. The OPAx625 has 120-MHz gain bandwidth, 2.5-nV/ \sqrt{Hz} input-referred noise, and consumes just 2 mA of quiescent current in high-drive mode. In addition, the OPAx625 also has an offset voltage of 100 μ V (max) and offset voltage drift of 1 μ V/°C (typ). This combination of high precision, high speed, and low noise makes this device suitable for use as an input driver for high-precision, high-throughput SAR ADCs such as ADS88xx family of SAR ADC, as shown in Figure 73.

In high-drive mode, the OPAx625 is fully specified as a wideband, low-noise, low-distortion precision amplifier. High-drive mode is the primary mode of operation of the OPAx625 when driving the inputs of a SAR ADC during the signal acquisition period just before the start of the conversion period. Placing the OPAx625 into the high-drive mode before the acquisition period is complete, and before the start of the conversion period, allows the OPAx625 to settle to the final value just prior to the conversion. When the ADC is converting the input signal, and therefore no longer acquiring the signal, place the OPAx625 into the low-power mode to reduce system power. Using low-power mode allows the OPAx625 power consumption to scale directly with the sample rate.

The OPAx625 is unique in that the switching between the modes occurs in 170 ns (typ). This fast switching is achieved by the architecture of the OPAx625 during low-power mode; see the *Low-Power Mode* section for more information.



Device Functional Modes (continued)

8.4.2 Low-Power Mode

Place the OPAx625 low-power mode by applying a logic level high to the MODE pin. The MODE pin can be driven by a GPIO from the system controller, from discrete logic gates, or can be connected to directly to the V+pin. Do not leave the MODE pin floating. When driving the MODE pin from a microcontroller GPIO, make sure that the GPIO is not placed into a high-impedance state. Placing the GPIO into a high-impedance state results in the MODE pin essentially floating, and is not recommended. Do not allow the MODE pin voltage to exceed the voltage at the V+ pin; see the Absolute Maximum Ratings for the allowable voltage to drive the MODE pin.

In low-power mode, the OPAx625 is fully specified as a general-purpose operational amplifier. The MODE signal can be controlled so that the OPAx625 is placed in high-drive mode just before the ADC enters the acquisition phase. This configuration makes sure that the voltage on the antialiasing filter capacitor settles to the required precision before the acquisition period is complete. The power consumed by the OPAx625 scales with the throughput of the system when operated in this manner. This feature is extremely useful in power-critical applications and variable-throughput data acquisition systems.

The OPAx625 is unique in that the switching between the modes occurs in 170 ns (typ). This fast switching is achieved by the architecture of the OPAx625 during low-power mode. Most amplifiers in power-down or shutdown mode consume very minimal power, but are also not operating in a linear fashion. For example, the output of a typical amplifier, when disabled, can be placed into a high-impedance state, and thus unable to drive any load whatsoever. Switching from a shut-down state to a linear state requires charging internal capacitances and bias points to a level within the linear operating range. Typically, this switch can take several microseconds or longer. This problem is solved with the OPAx625. The OPAx625 operates as a linear operational amplifier in low-power mode, and the output tracks the input signal, but with a lower bandwidth and slightly higher offset and noise. Switching from low-power mode to high-drive mode and settling to 16-bit levels occurs in 170 ns (typ) as a result of maintaining operation in a linear fashion throughout the duration of each mode. This configuration allows for dynamic power scaling, while still maintaining high throughput rates.

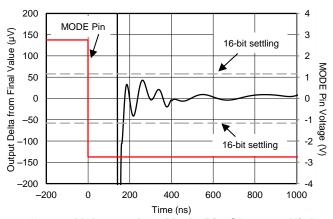


Figure 72. Output Voltage when Mode Pin Changes High to Low



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The OPAx625 is a precision, high-speed, voltage-feedback operational amplifier. Fast settling to 16-bit levels, low THD, and low noise make the OPAx625 suitable for driving SAR ADC inputs and buffering precision voltage references. With a wide power-supply voltage range from 2.7 V to 5.5 V, and operating from –40°C to +125°C, the OPAx625 is suitable for a variety of high-speed, industrial applications. The following sections show application information for the OPAx625. For simplicity, power-supply decoupling capacitors are not shown in these diagrams.

9.2 Typical Applications

9.2.1 Single-Supply, 16-Bit, 1-MSPS SAR ADC Driver

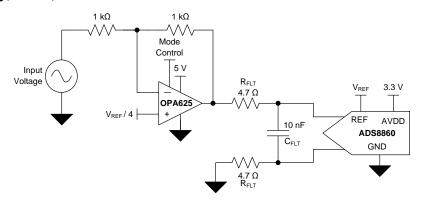


Figure 73. Single-Supply, 16-Bit, 1-MSPS SAR ADC Driver

9.2.1.1 Design Requirements

SAR ADCs, such as the ADS8860, use sampling capacitors on the data converter input. During the signal acquisition phase, these sampling capacitors are connected to the ADC analog input terminals, AINP and AINN, through a set of switches. After the acquisition period has elapsed, the internal sampling capacitors are disconnected from the input terminals and connected to the input of the ADC through a second set of switches, during this period the ADC is performing the analog-to-digital conversion. Figure 74 illustrates this architecture.

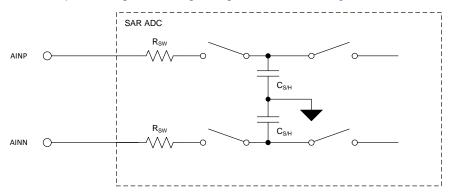


Figure 74. Simplified SAR ADC Input



Typical Applications (continued)

The SAR ADC inputs and sampling capacitors must be driven by the OPA625 to 16-bit levels within the acquisition time of the ADC. For the example illustrated in Figure 73, the OPA625 is used to drive the ADS8860 at a sample rate of 1 MSPS.

9.2.1.2 Detailed Design Procedure

The circuit illustrated in Figure 73 consists of the SAR ADC driver, a low-pass filter and the SAR ADC. The SAR ADC driver circuit consists of an OPA625 configured in an inverting gain of 1. The filter consists of R_{FLT} and C_{FLT} , connected between the output of the OPA625 and input of the ADS8860. Selecting the proper values for each of these passive components is critical to obtain the best performance from the ADC. Capacitor C_{FLT} serves as a charge reservoir, providing the necessary charge to the ADC sampling capacitors. The dynamic load presented by the ADC creates a glitch on the filter capacitor, C_{FLT} . To minimize the magnitude of this glitch, choose a value for C_{FLT} large enough to maintain a glitch amplitude of less than 100 mV. Maintaining such a low glitch amplitude at the amplifier output makes sure that the amplifier remains in the linear operating region, and results in a minimum settling time. Using Equation 6, a 10-nF capacitor is selected for C_{FLT} .

$$C_{\mathsf{FLT}} \ge 15 \times C_{\mathsf{SH}} \tag{6}$$

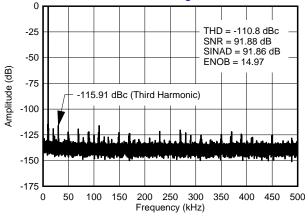
Connecting a 10-nF capacitor directly to the output of the OPA625 degrades the OPA625 phase margin and results in stability and settling-time problems. To properly drive the 10-nF capacitor, use a series resistor (R_{FLT}) to isolate the capacitor, C_{FLT} , from the OPA625. R_{FLT} must be sized based upon several constraints. To determination a suitable value for R_{FLT} , consider the impact upon the THD due to the voltage divider effect from R_{FLT} reacting with the switch resistance (R_{SW}) of the ADC input circuit, as well as the impact of the output impedance upon amplifier stability. In this example, 4.7- Ω resistors are selected. In this design example, Figure 16 can be used to estimate a suitable value for R_{ISO} . R_{ISO} represents the total resistance in series with C_{FLT} , and in this example is equivalent to 2 × R_{FLT} .



For step-by-step design procedure, circuit schematics, bill of materials, printed circuit board (PCB) files, simulation results, and test results, refer to TI Precision Design, TIDU014, "Power-optimized 16-bit 1MSPS Data Acquisition Block for Lowest Distortion and Noise Reference Design".

9.2.1.3 Application Curves

Figure 75 illustrates the performance of the circuit shown in Figure 73.



4096-point FFT at 1 MSPS, $f_{IN} = 10 \text{ kHz}$, $V_{IN} = 1.5 \text{ V}_{RMS}$

Figure 75. ADC Output FFT for Figure 73



9.2.2 Single-Supply, 16-Bit, 1-MSPS, Multiplexed, SAR ADC Driver

In order to operate a high-resolution, 16-bit ADC at its maximum throughput, the full-scale voltage step must settle to better than 16-bit accuracy at the ADC inputs within the minimum specified acquisition time (t_{ACQ}). This settling imposes very stringent requirements on the driver amplifier in terms of large-signal bandwidth, slew rate, and settling time. Figure 76 illustrates a typical multiplexed ADC driver application using the OPA625.

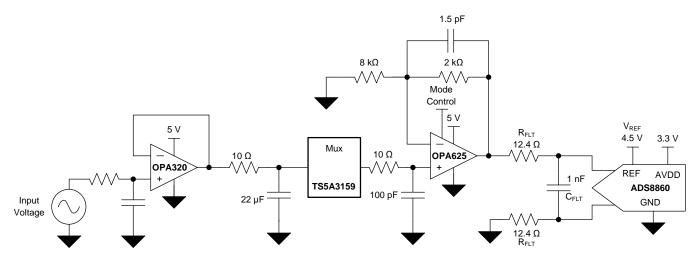


Figure 76. Single-Supply, 16-Bit, 1-MSPS, Multiplexed, SAR ADC Driver

9.2.2.1 Design Requirements

To optimize this circuit for performance, this design does not allow any large signal input transients at the inputs of the driver circuit for a small quiet-time period (t_{QT}) towards the end of the previous conversion. The input step voltage can appear anytime from the beginning of conversion (CONVST rising edge) until the elapse of a half cycle time $(0.5 \times t_{CYC})$. This timing constraint on the input step allows a minimum settling time of $(t_{QT} + t_{ACQ})$ for the ADC input to settle within the required accuracy, in the worst-case scenario. This provides more time for the amplifier's output to slew and settle within the required accuracy before the next conversion starts. Figure 77 illustrates this timing sequence.

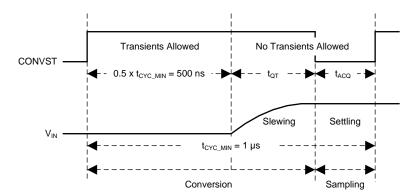


Figure 77. Timing Diagram for Input Signals



9.2.2.2 Detailed Design Procedure

An ADC input driver circuit mainly consists of two parts: a driving amplifier and a fly-wheel RC filter. The amplifier is used for signal conditioning of the input voltage and its low output impedance provides a buffer between the signal source and the ADC input. The RC filter helps attenuate the sampling charge-injection from the switched-capacitor input stage of the ADC as well as acts as an anti-aliasing filter to band-limit the wideband noise contributed by the front-end circuit. The design of the ADC input driver involves optimizing the bandwidth of the circuit, driven primarily by the following requirements:

- The R_{FLT}C_{FLT} filter bandwidth should be low to band-limit the noise fed into the input of the ADC thereby increasing the signal-to-noise ratio (SNR) of the system.
- The overall system bandwidth should be large enough to accommodate optimal settling of the input signal at the ADC input before the start of conversion.

C_{FLT} is chosen based upon Equation 7 . C_{FLT} is chosen to be 1 nF.

$$C_{\mathsf{FLT}} \ge 15 \times C_{\mathsf{SH}}$$
 (7)

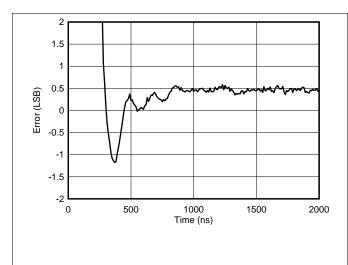
Connecting a 1-nF capacitor directly to the output of the OPA625 would degrade the OPA625 phase margin and result in stability and settling time problems. To properly drive the 1-nF capacitor, a series resistor, R_{FLT} , is used to isolate the capacitor, C_{FLT} , from the OPA625. R_{FLT} must be sized based upon several constraints. To determination a suitable value for R_{FLT} , the system designer must consider the impact upon the THD due to the voltage divider effect from R_{FLT} reacting with the switch resistance, R_{SW} , of the ADC input circuit as well as the impact of the output impedance upon amplifier stability. In this example 12.4- Ω resistors are selected. In this design example, Figure 15 can be used to estimate a suitable value for R_{ISO} . R_{ISO} represents the total resistance in series with C_{FLT} , which in this example is equivalent to 2 × R_{FLT} .



For step-by-step design procedure, circuit schematics, bill of materials, printed circuit board (PCB) files, simulation results, and test results, refer to TI Precision Design, TIDU012, "Power-optimized 16-bit 1MSPS Data Acquisition Block for Lowest Distortion and Noise Reference Design".

9.2.2.3 Application Curves

Figure 78 illustrates the performance of the circuit shown in Figure 76.





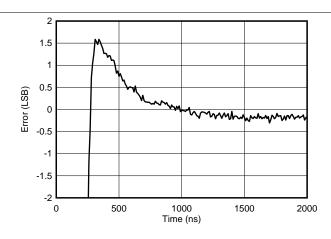


Figure 79. Negative Transient Response for Figure 76



10 Power Supply Recommendations

The OPAx625 is specified for operation from 2.7 V to 5.5 V (±1.35 V to ±2.75 V); many specifications apply from –40°C to +125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the Typical Characteristics. Place bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the *Layout* section.

CAUTION

Supply voltages larger than 6 V can cause permanent damage to the device. See to the *Absolute Maximum Ratings* section.

11 Layout

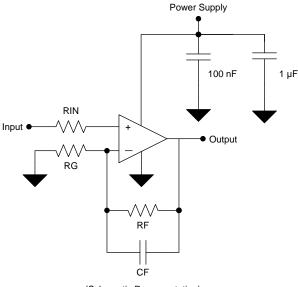
11.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Use bypass capacitors to reduce the noise coupled from the power supply. Connect low ESR, ceramic, bypass capacitors between the power supply pins (V+ and V-) and the ground plane. Place the bypass capacitors as close to the device as possible with the 100-nF capacitor closest to the device, as indicated in Figure 80. For single-supply applications, bypass capacitors on the V- pin are not required.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes.
 A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital
 and analog grounds paying attention to the flow of the ground current. For more detailed information refer to
 SLOA089, Circuit Board Layout Techniques.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as
 possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular
 as opposed to in parallel with the noisy trace.
- Minimize parasitic coupling between +IN and OUT for best ac performance.
- Place the external components as close to the device as possible. As shown in Figure 80, keeping RF, CF, and RG close to the inverting input will minimize parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the plastic package. Following any aqueous PCB cleaning process, bake the PCB assembly to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.



11.2 Layout Example



(Schematic Representation)

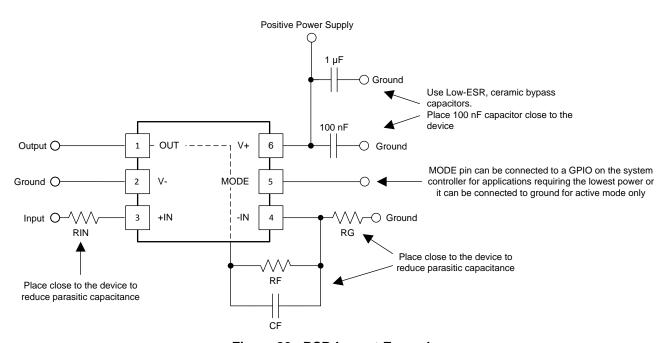


Figure 80. PCB Layout Example



12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 TINA-TI™ (Free Software Download)

TINA™ is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI is a free, fully-functional version of the TINA software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Analog eLab Design Center, TINA-TI offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

12.1.1.2 TI Precision Designs

TI Precision Designs are available online at http://www.ti.com/ww/en/analog/precision-designs/. TI Precision Designs are analog solutions created by TI's precision analog applications experts and offer the theory of operation, component selection, simulation, complete PCB schematic and layout, bill of materials, and measured performance of many useful circuits.

12.2 Documentation Support

12.2.1 Related Documentation

16-Bit, 1MSPS Multiplexed Data Acquisition Reference Design Guide, TIDUAD9

12.3 Related Links

Table 1 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

| PARTS | PRODUCT FOLDER | SAMPLE & BUY | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY |
|---------|----------------|--------------|---------------------|------------------|---------------------|
| OPA625 | Click here | Click here | Click here | Click here | Click here |
| OPA2625 | Click here | Click here | Click here | Click here | Click here |

12.4 Community Resources

The following links connect to TI community resources. Linked contents are provided AS IS by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Product Folder Links: OPA625 OPA2625

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

ubinii Documentation Feedback



12.5 Trademarks

E2E is a trademark of Texas Instruments.

TINA-TI is a trademark of Texas Instruments, Inc and DesignSoft, Inc.

TINA is a trademark of DesignSoft, Inc.

All other trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: OPA625 OPA2625



PACKAGE OPTION ADDENDUM



10-Dec-2020

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|---------------------|--------------|----------------------|---------|
| 004000510000 | A OTIV (E | \/000D | D00 | 40 | 0500 | D-110 0 0 | (6) | 1 0 0000 4 VEAD | 40.1- 405 | 0005 | |
| OPA2625IDGSR | ACTIVE | VSSOP | DGS | 10 | 2500 | RoHS & Green | NIPDAUAG | Level-2-260C-1 YEAR | -40 to 125 | 2625 | Samples |
| OPA2625IDGST | ACTIVE | VSSOP | DGS | 10 | 250 | RoHS & Green | NIPDAUAG | Level-2-260C-1 YEAR | -40 to 125 | 2625 | Samples |
| | | | | | | | | | | | Samples |
| OPA625IDBVR | ACTIVE | SOT-23 | DBV | 6 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | O625 | Samples |
| | | | | | | | | | | | bampies |
| OPA625IDBVT | ACTIVE | SOT-23 | DBV | 6 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | O625 | Samples |
| | | | | | | | | | | | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 17-Jul-2020

TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| BO | Dimension designed to accommodate the component length |
| | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| OPA2625IDGSR | VSSOP | DGS | 10 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| OPA2625IDGST | VSSOP | DGS | 10 | 250 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| OPA625IDBVR | SOT-23 | DBV | 6 | 3000 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| OPA625IDBVT | SOT-23 | DBV | 6 | 250 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |

PACKAGE MATERIALS INFORMATION

www.ti.com 17-Jul-2020



*All dimensions are nominal

| 7 till difficitional and framilian | | | | | | | |
|------------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| OPA2625IDGSR | VSSOP | DGS | 10 | 2500 | 366.0 | 364.0 | 50.0 |
| OPA2625IDGST | VSSOP | DGS | 10 | 250 | 366.0 | 364.0 | 50.0 |
| OPA625IDBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 180.0 | 18.0 |
| OPA625IDBVT | SOT-23 | DBV | 6 | 250 | 180.0 | 180.0 | 18.0 |



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187, variation BA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

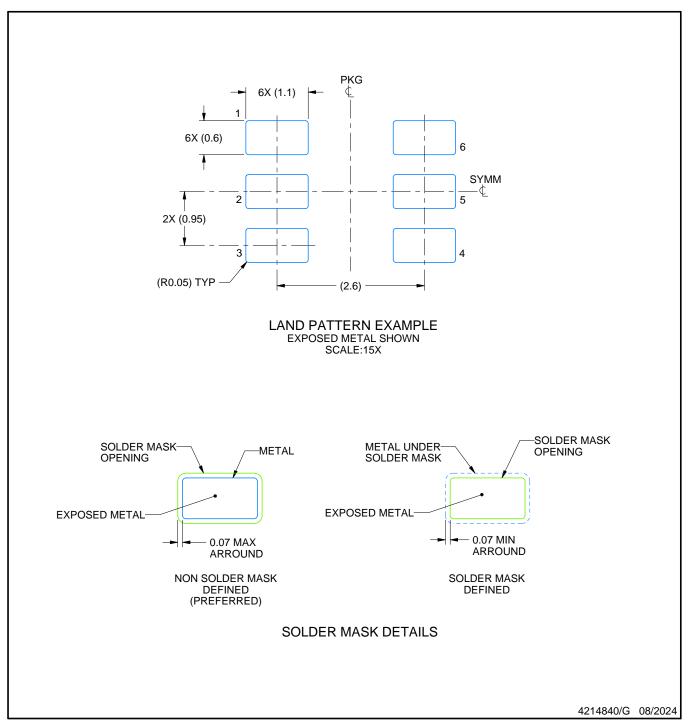
 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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